

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	115841	(SOI (silicon near5 insulat\$3))	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 19:27
L2	72073	1 and (source drain)	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 19:27
L3	45960	2 and gate	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 19:28
L4	217188	(STI (shallow near5 trench near5 isolat\$3))	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 19:28
L5	5690	3 and 4	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 16:33
L6	1706	5 and epitaxial\$3	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 16:33
L7	1661	6 and trench	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 16:33
L8	1669	6 and (trench recess groove)	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 16:34
L9	684	8 and (thermal near8 oxid\$3)	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 16:34
L10	797	8 and (thermal\$3 near8 oxid\$3)	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 16:34
L11	684	9 and 10	US-PGPU B; USPAT; USOCR	OR	ON	2005/06/21 16:35
L12	36576	(SOI (silicon near5 insulat\$3))	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/21 19:27
L13	7656	12 and (source drain)	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/21 19:28
L14	5837	13 and gate	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/21 19:28

L15	61	14 and (STI (shallow near5 trench near5 isolat\$3))	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2005/06/21 19:29
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